

ZXMP3A16G

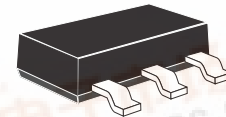
30V P-CHANNEL ENHANCEMENT MODE MOSFET

SUMMARY

$V_{(BR)DSS} = -30V$; $R_{DS(on)} = 0.045\Omega$; $I_D = -7.5A$

DESCRIPTION

This new generation of trench MOSFETs from Zetex utilizes a unique structure that combines the benefits of low on-resistance with fast switching speed. This makes them ideal for high efficiency, low voltage, power management applications.



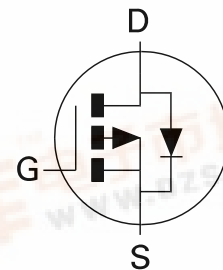
SOT223

FEATURES

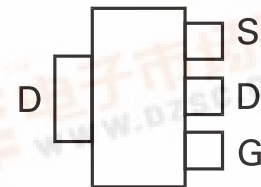
- Low on-resistance
- Fast switching speed
- Low threshold
- Low gate drive
- SOT223 package

APPLICATIONS

- DC-DC converters
- Power management functions
- Relay and solenoid driving
- Motor control



PINOUT



Top View

ORDERING INFORMATION

DEVICE	REEL SIZE	TAPE WIDTH	QUANTITY PER REEL
ZXMP3A16GTA	7"	12mm	1000 units
ZXMP3A16GTC	13"	12mm	4000 units

DEVICE MARKING

- ZXMP
3A16

ZXMP3A16G

ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	V_{DSS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ($V_{GS} = -10V$; $T_A = 25^\circ C$)(b) ($V_{GS} = -10V$; $T_A = 70^\circ C$)(b) ($V_{GS} = -10V$; $T_A = 25^\circ C$)(a)	I_D	-7.5 -6.0 -5.4	A
Pulsed Drain Current (c)	I_{DM}	-24.9	A
Continuous Source Current (Body Diode) (b)	I_S	-3.2	A
Pulsed Source Current (Body Diode)(c)	I_{SM}	-24.9	A
Power Dissipation at $T_A = 25^\circ C$ (a) Linear Derating Factor	P_D	2.0 16	W mW/ $^\circ C$
Power Dissipation at $T_A = 25^\circ C$ (b) Linear Derating Factor	P_D	3.9 31	W mW/ $^\circ C$
Operating and Storage Temperature Range	T_j, T_{stg}	-55 to +150	$^\circ C$

THERMAL RESISTANCE

PARAMETER	SYMBOL	VALUE	UNIT
Junction to Ambient (a)	$R_{\theta JA}$	62.5	$^\circ C/W$
Junction to Ambient (b)	$R_{\theta JA}$	32.2	$^\circ C/W$

NOTES:

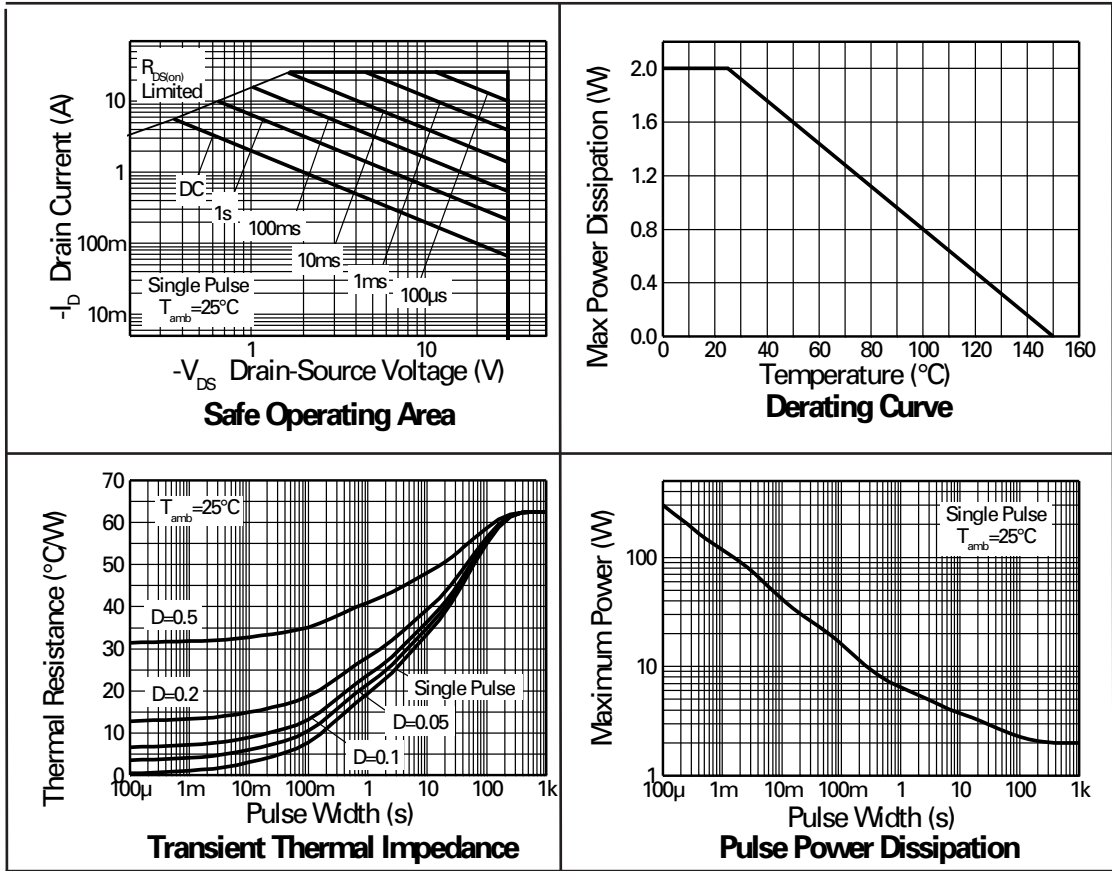
(a) For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions

(b) For a device surface mounted on FR4 PCB measured at $t \leq 10$ secs.

(c) Repetitive rating 25mm x 25mm FR4 PCB, $D=0.05$ pulse width limited by maximum junction temperature.

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TYPICAL CHARACTERISTICS



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ELECTRICAL CHARACTERISTICS (at $T_A = 25^\circ\text{C}$ unless otherwise stated).

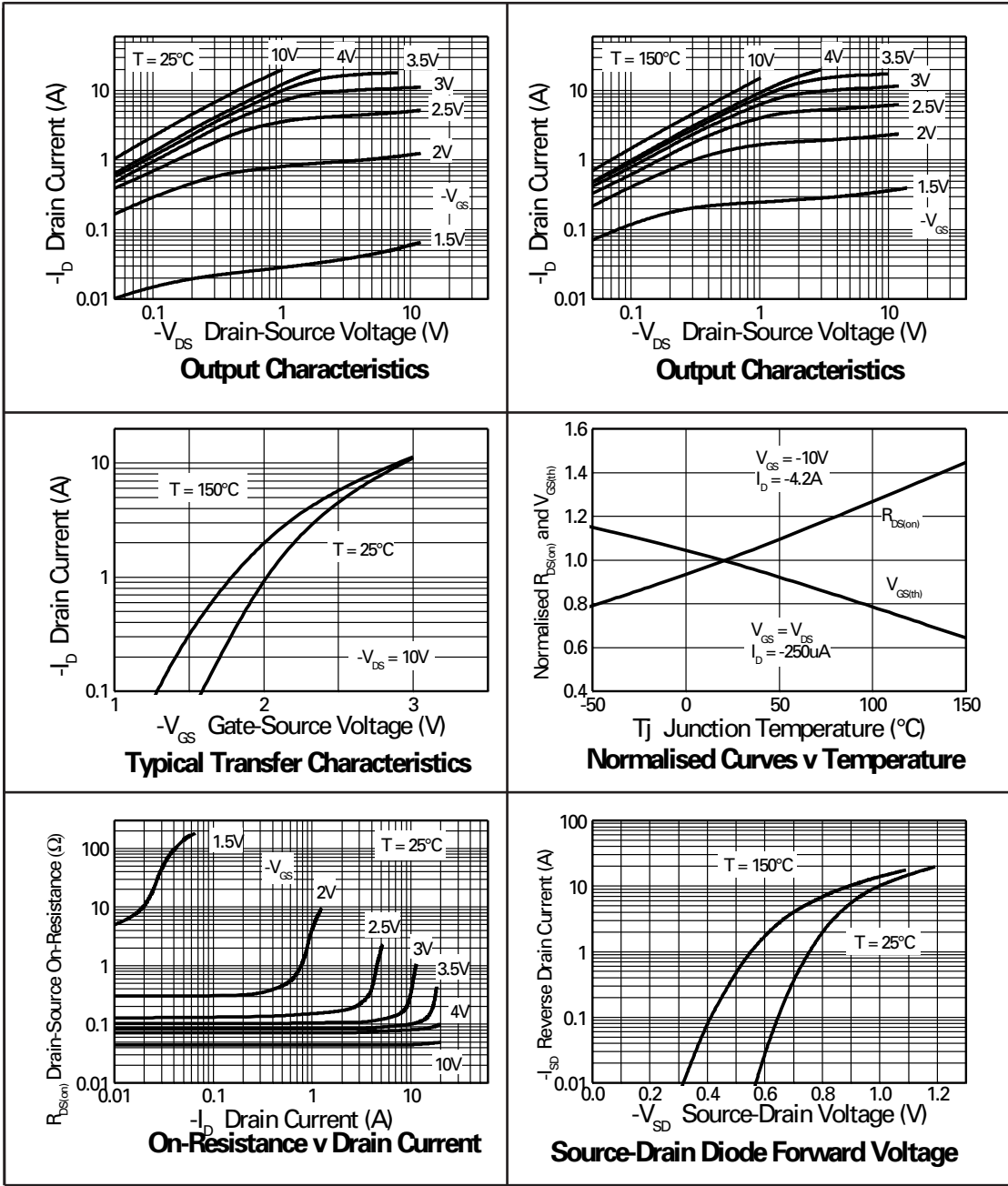
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
STATIC						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	-30			V	I _D =-250μA, V _{GS} =0V
Zero Gate Voltage Drain Current	I _{DSS}			-1	μA	V _{DS} =-30V, V _{GS} =0V
Gate-Body Leakage	I _{GSS}			100	nA	V _{GS} =±20V, V _{DS} =0V
Gate-Source Threshold Voltage	V _{GS(th)}	-1.0			V	I _D =-250μA, V _{DS} = V _{GS}
Static Drain-Source On-State Resistance (1)	R _{DS(on)}			0.045 0.070	Ω Ω	V _{GS} =-10V, I _D =-4.2A V _{GS} =-4.5V, I _D =-3.4A
Forward Transconductance (1)(3)	g _{fs}		9.2		S	V _{DS} =-15V,I _D =-4.2A
DYNAMIC (3)						
Input Capacitance	C _{iss}		1022		pF	V _{DS} =-15V, V _{GS} =0V, f=1MHz
Output Capacitance	C _{oss}		267		pF	
Reverse Transfer Capacitance	C _{rss}		229		pF	
SWITCHING(2) (3)						
Turn-On Delay Time	t _{d(on)}		3.8		ns	V _{DD} =-15V, I _D =-1A R _G =6.0Ω, V _{GS} =-10V
Rise Time	t _r		6.5		ns	
Turn-Off Delay Time	t _{d(off)}		37.1		ns	
Fall Time	t _f		21.4		ns	
Gate Charge	Q _g		17.2		nC	V _{DS} =-15V,V _{GS} =-5V, I _D =-4.2A
Total Gate Charge	Q _g		29.6		nC	V _{DS} =-15V,V _{GS} =-10V, I _D =-4.2A
Gate-Source Charge	Q _{gs}		2.8		nC	
Gate-Drain Charge	Q _{gd}		8.6		nC	
SOURCE-DRAIN DIODE						
Diode Forward Voltage (1)	V _{SD}		-0.85	-0.95	V	T _J =25°C, I _S =-3.6A, V _{GS} =0V
Reverse Recovery Time (3)	t _{rr}		21.7		ns	T _J =25°C, I _F =-2A, di/dt= 100A/μs
Reverse Recovery Charge (3)	Q _{rr}		16.1		nC	

NOTES

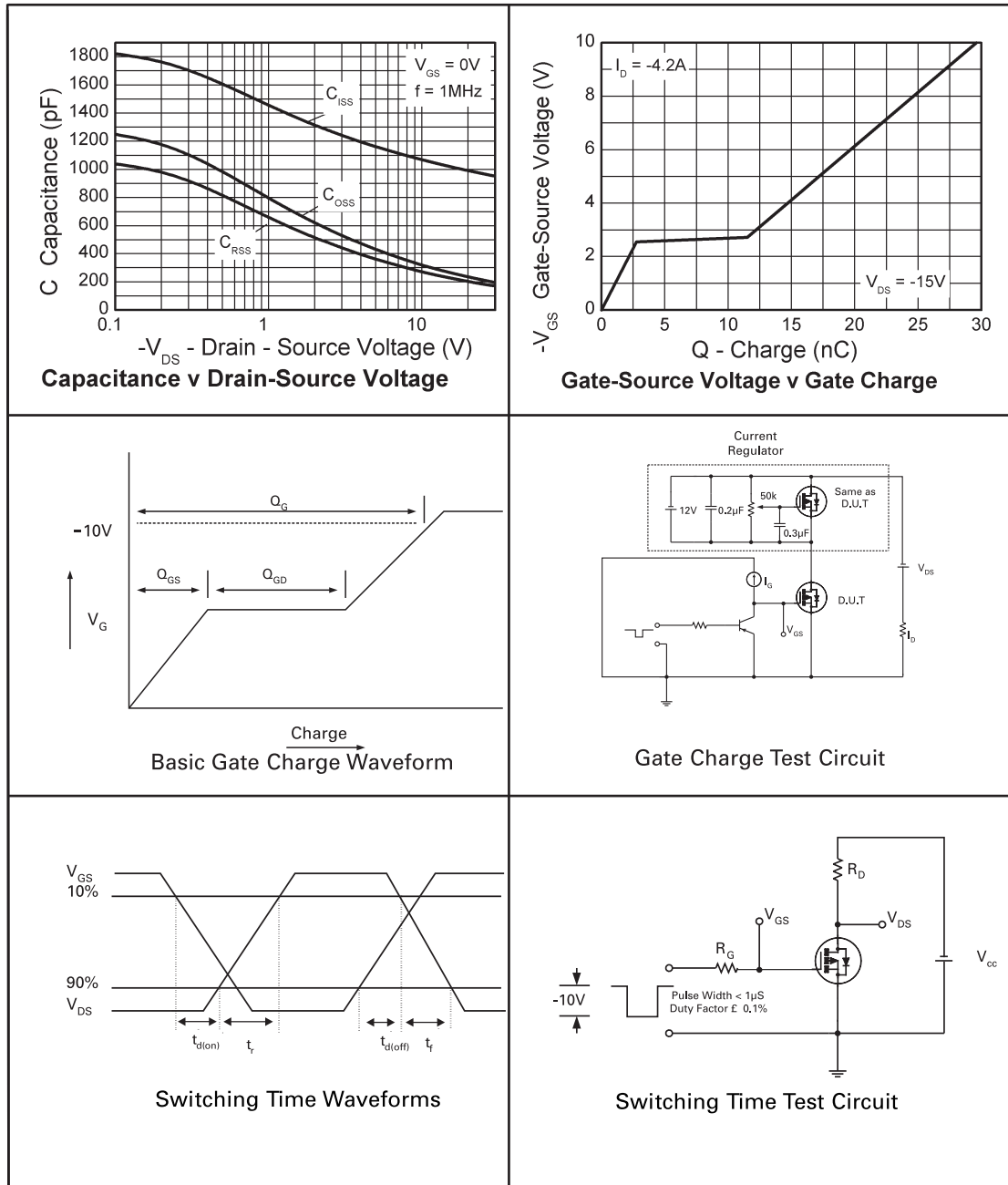
- (1) Measured under pulsed conditions. Width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.
- (2) Switching characteristics are independent of operating junction temperature.
- (3) For design aid only, not subject to production testing.

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TYPICAL CHARACTERISTICS



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"Active" Product status recommended for new designs

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"Not recommended for new designs" Device is still in production to support existing designs and production

"Obsolete" Production has been discontinued

Datasheet status key:

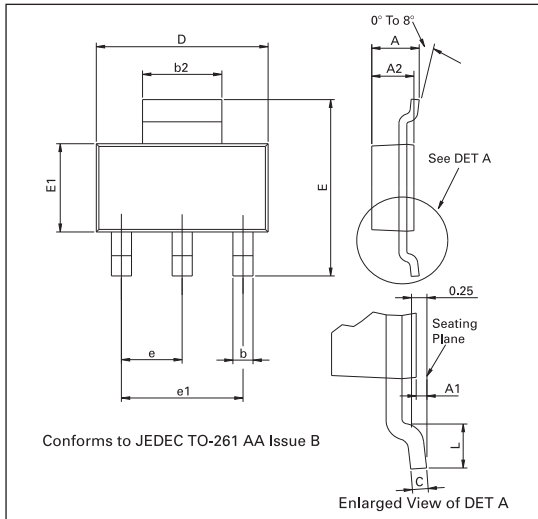
"Draft version" This term denotes a very early datasheet version and contains highly provisional information, which may change in any manner without notice.

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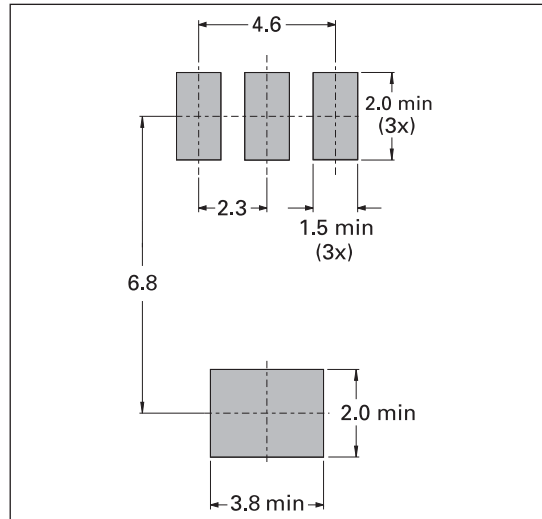
"Issue" This term denotes an issued datasheet containing finalized specifications. However, changes to specifications may occur, at any time and without notice.

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PACKAGE OUTLINE



PAD LAYOUT DETAILS



PACKAGE DIMENSIONS

DIM	Millimeters		Inches		DIM	Millimeters		Inches	
	Min	Max	Min	Max		Min	Max	Min	Max
A	-	1.80	-	0.071	e	2.30 BSC		0.0905 BSC	
A1	0.02	0.10	0.0008	0.004	e1	4.60 BSC		0.181 BSC	
b	0.66	0.84	0.026	0.033	E	6.70	7.30	0.264	0.287
b2	2.90	3.10	0.114	0.122	E1	3.30	3.70	0.130	0.146
C	0.23	0.33	0.009	0.013	L	0.90	-	0.355	-
D	6.30	6.70	0.248	0.264	-	-	-	-	-

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